

## High Speed, Precision JFET Input Operational Amplifier

### FEATURES

- Guaranteed Slew Rate       $23V/\mu s$  Min.
- Guaranteed Offset Voltage       $250\mu V$  Max.
- $-55^{\circ}C$  to  $125^{\circ}C$
- Guaranteed Drift       $750\mu V$  Max.
- Guaranteed Bias Current       $5\mu V/\text{ }^{\circ}C$  Max.
- $70^{\circ}C$
- $125^{\circ}C$
- Gain-Bandwidth Product       $180pA$  Max.
- Settling Time to 0.05% (10V Step)       $4nA$  Max.
- $8.5MHz$  Typ.
- $0.9\mu s$  Typ.

### DESCRIPTION

The LT1022 JFET input operational amplifier combines high speed and precision performance.

A  $26V/\mu s$  slew rate and  $8.5MHz$  gain-bandwidth product are simultaneously achieved with offset voltage of typically  $80\mu V$ ,  $1.5\mu V/\text{ }^{\circ}C$  drift, bias currents of  $50pA$  at  $70^{\circ}C$ ,  $500pA$  at  $125^{\circ}C$ . The output delivers  $20mA$  of load current without gain degradation.

The  $250\mu V$  maximum offset voltage specification represents less than  $\frac{1}{2}$  least significant bit error in a 14-bit, 10V system.

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### APPLICATIONS

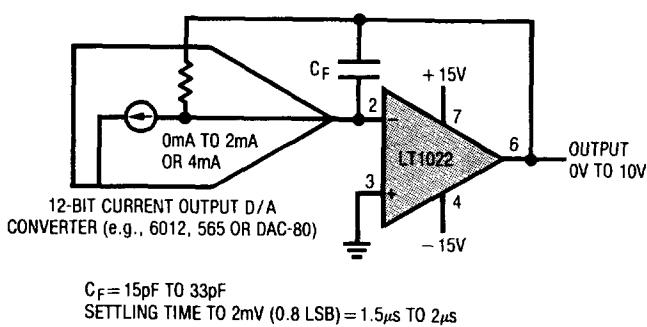
- Fast D/A Output Amplifiers (12, 14, 16 Bits)
- High Speed Instrumentation
- Fast, Precision Sample and Hold
- Voltage-to-Frequency Converters
- Logarithmic Amplifiers

The LT1022A meets or exceeds all OP-16A and OP-16E specifications. It is faster and more accurate without stability problems at cold temperatures.

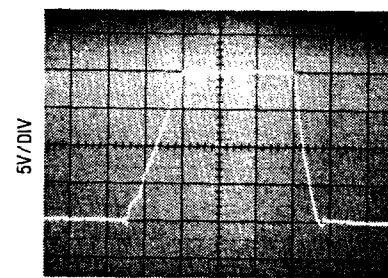
The LT1022 can be used as the output amplifier for 12-bit current output D/A converters, as shown below.

For a more accurate, lower power dissipation, but slower JFET input op amp, please refer to the LT1055 data sheet.

12-Bit Voltage Output D/A Converter



Large Signal Response



**ABSOLUTE MAXIMUM RATINGS**

Supply Voltage . . . . .	$\pm 20V$
Differential Input Voltage . . . . .	$\pm 40V$
Input Voltage . . . . .	$\pm 20V$
Output Short Circuit Duration . . . . .	Indefinite
Operating Temperature Range	
LT1022AM / 1022M . . . . .	-55°C to 125°C
LT1022AC / 1022C . . . . .	0°C to 70°C
Storage Temperature Range	
All Devices . . . . .	-65°C to 150°C
Lead Temperature (Soldering, 10 sec.) . . . . .	300°C

**PACKAGE/ORDER INFORMATION**

TOP VIEW	ORDER PART NUMBER
	LT1022AMH LT1022MH LT1022ACH LT1022CH
	LT1022CN8

**ELECTRICAL CHARACTERISTICS**

$V_S = \pm 15V$ ,  $T_A = 25^\circ C$ ,  $V_{CM} = 0V$  unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS	LT1022AM LT1022AC			LT1022M LT1022CH LT1022CN8			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{OS}$	Input Offset Voltage (Note 1)	H Package N8 Package	—	80	250	—	100	600	$\mu V$
			—	—	—	—	160	1000	$\mu V$
$I_{OS}$	Input Offset Current	Fully Warmed Up	—	2	10	—	2	20	pA
$I_B$	Input Bias Current	Fully Warmed Up $V_{CM} = +10V$	—	$\pm 10$	$\pm 50$	—	$\pm 10$	$\pm 50$	pA
			—	+30	+100	—	+30	+150	pA
	Input Resistance—Differential —Common-Mode	$V_{CM} = -11V$ to $+8V$ $V_{CM} = +8V$ to $+11V$	—	$10^{12}$	—	—	$10^{12}$	—	$\Omega$
			—	$10^{12}$	—	—	$10^{12}$	—	$\Omega$
			—	$10^{11}$	—	—	$10^{11}$	—	$\Omega$
	Input Capacitance		—	4	—	—	4	—	pF
$e_n$	Input Noise Voltage	0.1Hz to 10Hz	—	2.5	—	—	2.8	—	$\mu V_{p-p}$
$e_n$	Input Noise Voltage Density	$f_0 = 10Hz$ (Note 2) $f_0 = 1kHz$ (Note 3)	—	28	50	—	30	60	$nV/\sqrt{Hz}$
$i_n$	Input Noise Current Density	$f_0 = 10Hz$ , $1kHz$ (Note 4)	—	1.8	4	—	1.8	4	$fA/\sqrt{Hz}$
$A_{VOL}$	Large Signal Voltage Gain	$V_0 = \pm 10V$ $R_L = 2k$ $R_L = 1k$	150 130	400 300	—	120 100	400 300	—	$V/mV$
					—	100	300	—	$V/mV$
	Input Voltage Range		$\pm 10.5$	$\pm 12$	—	$\pm 10.5$	$\pm 12$	—	V
CMRR	Common-Mode Rejection Ratio	$V_{CM} = \pm 10.5V$	86	94	—	82	92	—	dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 10V$ to $\pm 18V$	88	104	—	86	102	—	dB
$V_{OUT}$	Output Voltage Swing	$R_L = 2k$	$\pm 12$	$\pm 13.2$	—	$\pm 12$	$\pm 13.2$	—	V
SR	Slew Rate		23	26	—	18	24	—	$V/\mu s$
GBW	Gain-Bandwidth Product	$f = 1MHz$	—	8.5	—	—	8.0	—	MHz
$I_S$	Supply Current		—	5.2	7.0	—	5.2	7.0	mA
	Settling Time	$A = +1$ or $A = -1$ 10V Step to 0.05% 10V Step to 0.02%	—	0.9	—	—	0.9	—	$\mu s$
			—	1.3	—	—	1.3	—	$\mu s$
	Offset Voltage Adjustment Range	$R_{POT} = 100k$	—	$\pm 7$	—	—	$\pm 7$	—	mV

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## ELECTRICAL CHARACTERISTICS $V_S = \pm 15V, V_{CM} = 0V, 0^\circ C \leq T_A \leq 70^\circ C$ unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS	LT1022AC			LT1022CH LT1022CN8			UNITS	
			MIN	TYP	MAX	MIN	TYP	MAX		
$V_{OS}$	Input Offset Voltage (Note 1)	H Package N8 Package	●	—	140	480	—	180	1000	$\mu V$
			●	—	—	—	—	300	1700	$\mu V$
$A_{VOL}$	Average Temperature Coefficient of Input Offset Voltage	H Package N8 Package (Note 5)	●	—	1.3	5.0	—	1.8	9.0	$\mu V/^\circ C$
			●	—	—	—	—	3.0	15.0	$\mu V/^\circ C$
$I_{OS}$	Input Offset Current	Warmed Up, $T_A = 70^\circ C$	●	—	15	80	—	18	100	nA
$I_B$	Input Bias Current	Warmed Up, $T_A = 70^\circ C$	●	—	$\pm 50$	$\pm 200$	—	$\pm 60$	$\pm 250$	nA
$A_{VOL}$	Large Signal Voltage Gain	$V_0 = \pm 10V, R_L = 2k$	●	80	250	—	60	250	—	V/mV
CMRR	Common-Mode Rejection Ratio	$V_{CM} = \pm 10.4V$	●	85	93	—	80	91	—	dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 10V$ to $\pm 18V$	●	86	103	—	84	101	—	dB
$V_{OUT}$	Output Voltage Swing	$R_L = 2k$	●	$\pm 12$	$\pm 13.1$	—	$\pm 12$	$\pm 13.1$	—	V

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## ELECTRICAL CHARACTERISTICS $V_S = \pm 15V, V_{CM} = 0V, -55^\circ C \leq T_A \leq 125^\circ C$ unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS	LT1022AM			LT1022M			UNITS	
			MIN	TYP	MAX	MIN	TYP	MAX		
$V_{OS}$	Input Offset Voltage	(Note 1)	●	—	230	750	—	300	1500	$\mu V$
	Average Temperature Coefficient of Input Offset Voltage	(Note 5)	●	—	1.5	5.0	—	2.0	9.0	$\mu V/^\circ C$
$I_{OS}$	Input Offset Current	Warmed Up, $T_A = 125^\circ C$	●	—	0.3	2.0	—	0.30	3.0	nA
$I_B$	Input Bias Current	Warmed Up, $T_A = 125^\circ C$	●	—	$\pm 0.5$	$\pm 4.0$	—	$\pm 0.7$	$\pm 6.0$	nA
$A_{VOL}$	Large Signal Voltage Gain	$V_0 = \pm 10V, R_L = 2k$	●	40	120	—	35	120	—	V/mV
CMRR	Common-Mode Rejection Ratio	$V_{CM} = \pm 10.4V$	●	85	92	—	80	90	—	dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 10V$ to $\pm 17V$	●	86	102	—	84	100	—	dB
$V_{OUT}$	Output Voltage Swing	$R_L = 2k$	●	$\pm 12$	$\pm 12.9$	—	$\pm 12$	$\pm 12.9$	—	V

The ● denotes the specifications which apply over the full operating temperature range.

**Note 1:** Offset voltage is measured under two different conditions:

- (a) approximately 0.5 seconds after application of power;
- (b) at  $T_A = 25^\circ C$ , with the chip self-heated to approximately  $45^\circ C$  to account for chip temperature rise when the device is fully warmed up.

**Note 2:** 10Hz noise voltage density is sample tested on every lot of A grades. Devices 100% tested at 10Hz are available on request.

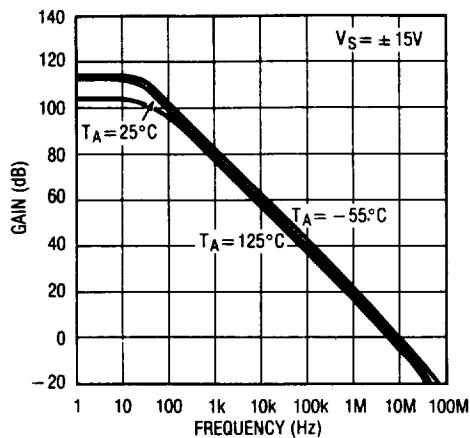
**Note 3:** This parameter is tested on a sample basis only.

**Note 4:** Current noise is calculated from the formula:  $i_n = (2qI_B)^{1/2}$ , where  $q = 1.6 \times 10^{-19}$  coulomb. The noise of source resistors up to  $1G\Omega$  swamps the contribution of current noise.

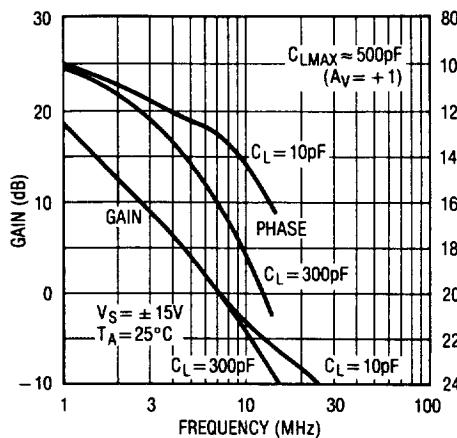
**Note 5:** Offset voltage drift with temperature is practically unchanged when the offset voltage is trimmed to zero with a 100k potentiometer between the balance terminals and the wiper tied to  $V^+$ . Devices tested to tighter drift specifications are available on request.

## TYPICAL PERFORMANCE CHARACTERISTICS

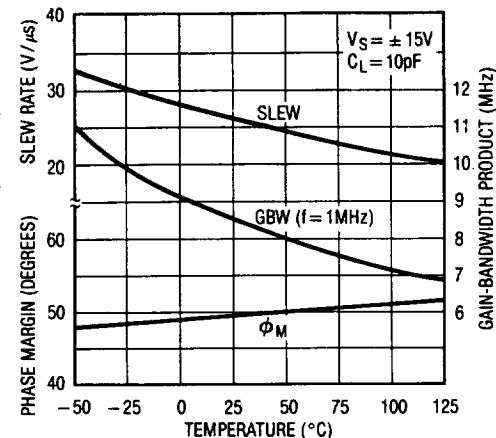
**Gain vs Frequency**



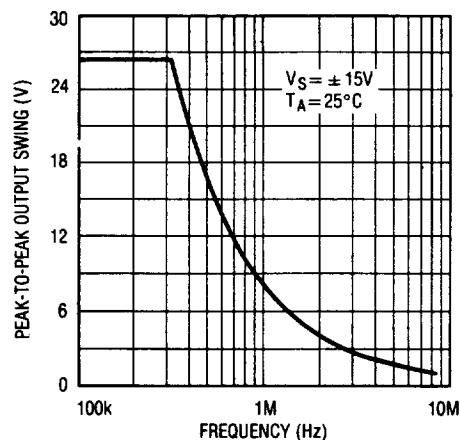
**Gain, Phase Shift vs Frequency**



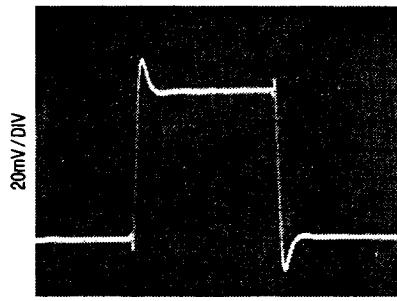
**Phase Margin, Gain Bandwidth Product, Slew Rate vs Temperature**



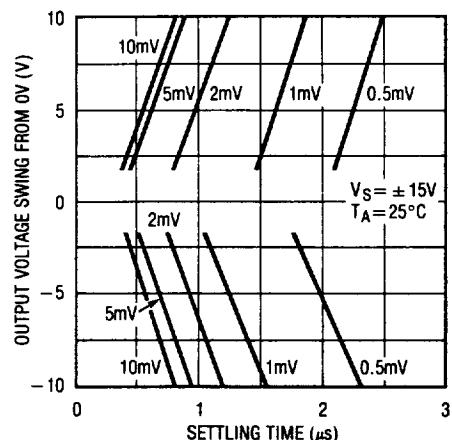
**Undistorted Output Swing vs Frequency**



**Small Signal Response**



**Settling Time**



The typical behavior of many LT1022 parameters is identical to the LT1056. Please refer to the LT1055/1056 data sheet for the following typical performance characteristics:

Input Bias and Offset Currents vs Temperature

Input Bias Current Over the Common-Mode Range

Distribution of Input Offset Voltage (H and N8 Package)

Distribution of Offset Voltage Drift with Temperature

Warm-Up Drift

Long Term Drift of Representative Units

0.1Hz to 10Hz Noise

Voltage Noise vs Frequency

Noise vs Chip Temperature

Output Impedance vs Frequency

Common-Mode Range vs Temperature

Common-Mode and Power Supply Rejections vs Temperature

Common-Mode Rejection Ratio vs Frequency

Power Supply Rejection Ratio vs Frequency

Voltage Gain vs Temperature

Supply Current vs Supply Voltage

Output Swing vs Load Resistance

Short Circuit Current vs Time

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## APPLICATIONS INFORMATION

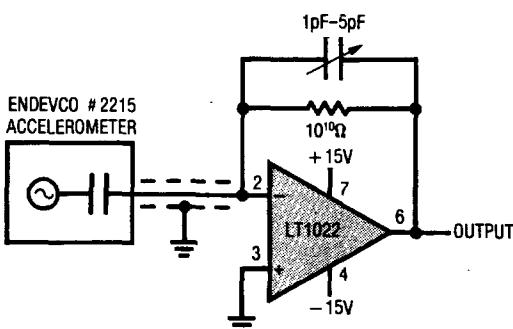
The LT1056 applications information is directly applicable to the LT1022. Please consult the LT1055/1056 data sheet for details on:

- (1) plug-in compatibility to industry standard devices
- (2) offset nulling
- (3) achieving picoampere/microvolt performance

- (4) phase-reversal protection
- (5) high speed operation (including settling time test circuit)
- (6) noise performance
- (7) simplified circuit schematic.

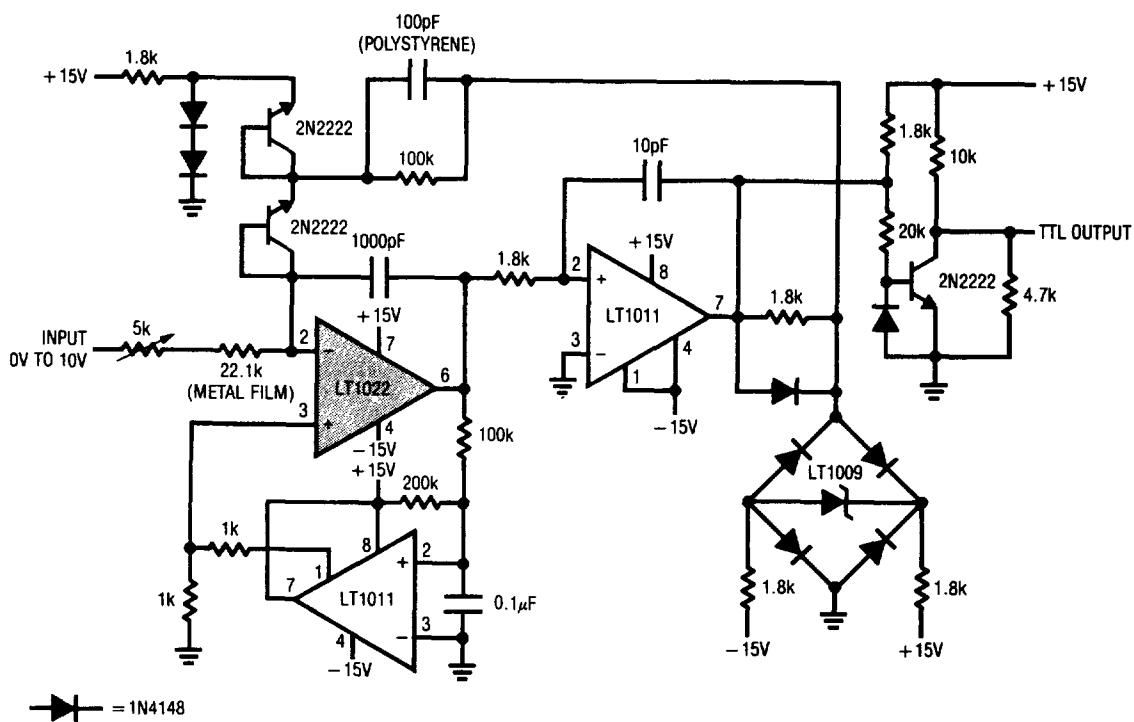
## TYPICAL APPLICATIONS

Fast Piezoelectric Accelerometer



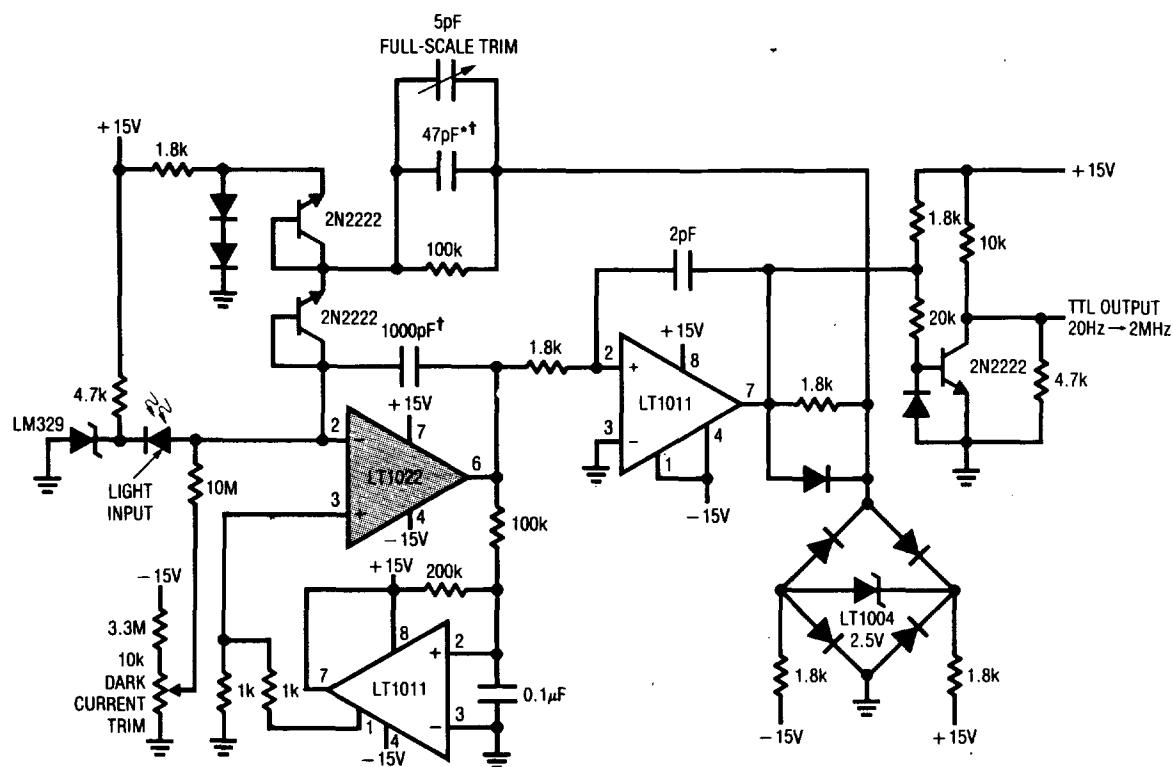
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10Hz to 1MHz Voltage-to-Frequency Converter



## **TYPICAL APPLICATIONS**

## **PN Photodiode-to-Frequency Converter**



SCALE FACTOR =  
1nW/Hz AT 900 NANOMETERS FROM 20nW TO 2mW

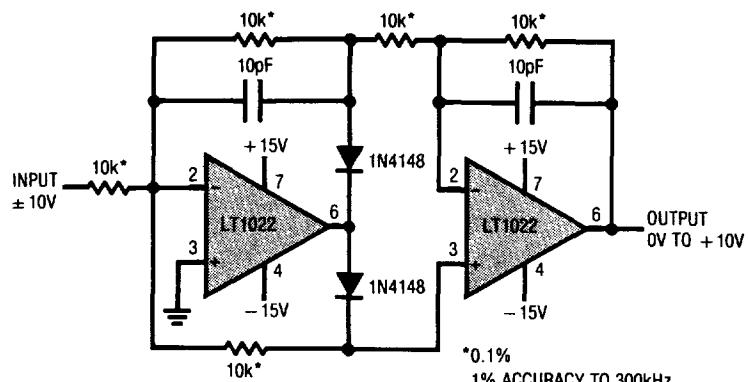
 = HEWLETT PACKARD PHOTODIODE HP5082-4204

→ = 1N4148

†POLYSTYRENE

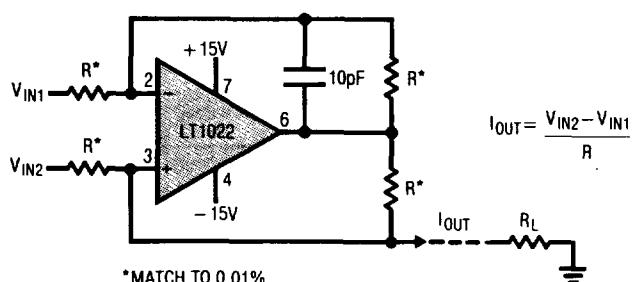
\*SELECT VALUE FOR 2mW IN = 2MHz OUT.

## **Wide Bandwidth Absolute Value Circuit**



\*0.1%  
1% ACCURACY TO 300kHz  
5% ACCURACY TO 700kHz

## Fast, Differential Input Current Source



\*MATCH TO 0.01%

#### **FULL-SCALE POWER BANDWIDTH**

= 1MHz FOR  $I_{OUTR} = 8Vp-p$

= 400kHz FOR  $I_{OUTR} = 20Vp-p$

MAXIMUM  $I_{out} = 10mA$ p-p

### COMMON-MODE VOLTAGE AT LT1

www.ijerph.org

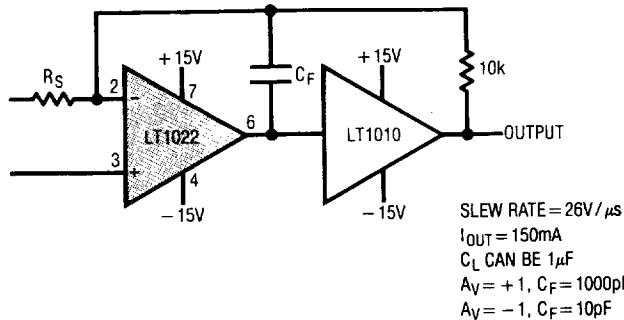
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10. The following table summarizes the results of the study.

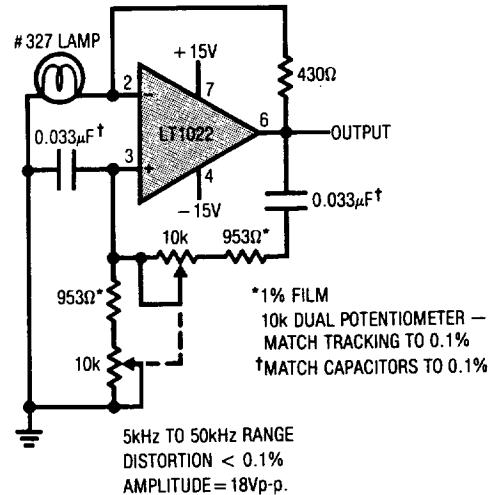
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## **TYPICAL APPLICATIONS**

## High Output Current Op Amp

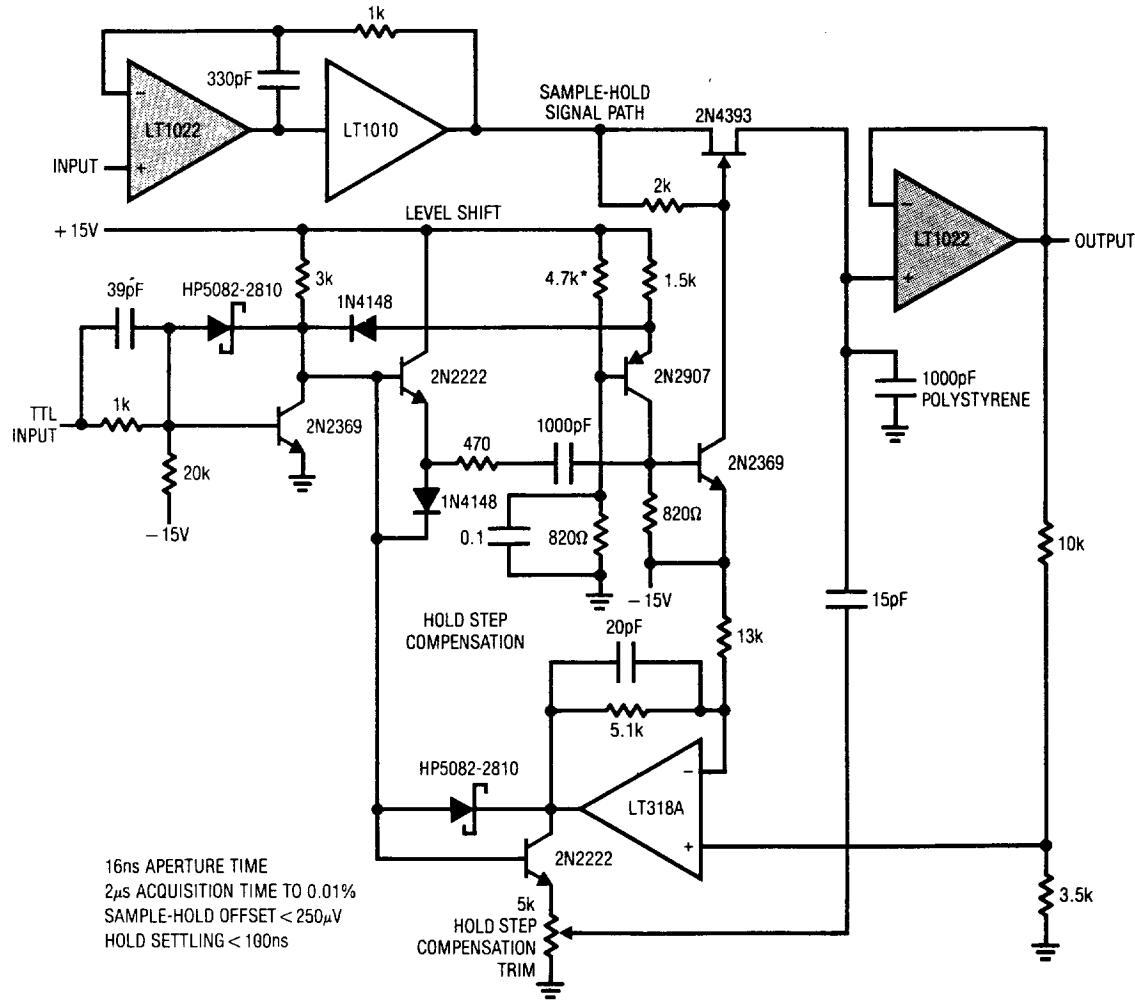


## **Low Distortion Sine Wave Oscillator**



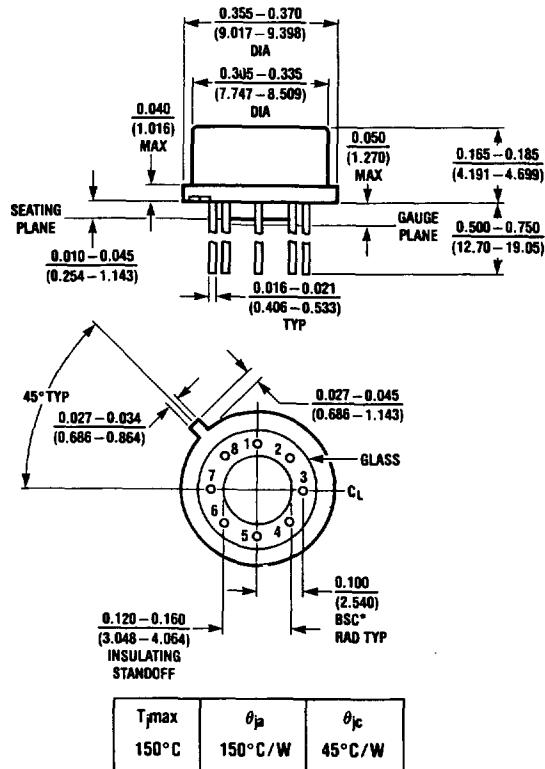
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## **Fast, Precision Sample-Hold**

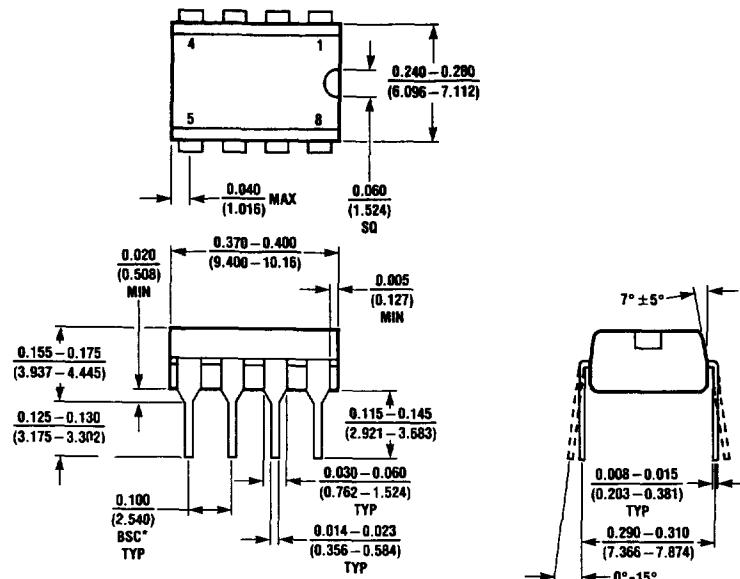


## PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.

### H Package Metal Can



### N8 Package 8 Lead Plastic



\*LEADS WITHIN 0.007 OF TRUE POSITION (TP) AT GAUGE PLANE

$T_j\max$ 100°C	$\theta_{ja}$ 130°C/W
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